Triacs BTA140B series

GENERAL DESCRIPTION

Glass passivated triacs in a plastic envelope suitable for surface mounting, intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

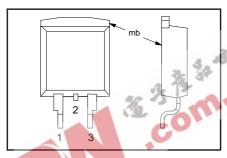
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
	BTA140B-	500	600	800	l
V_{DRM}	Repetitive peak off-state voltages	500	600	800	V
I _{T(RMS)} I _{TSM}	RMS on-state current Non-repetitive peak on-state	25 190	25 190	25 190	A A
	current				

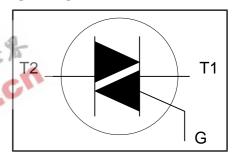
PINNING - SOT404

PIN	DESCRIPTION
1	main terminal 1
2	main terminal 2
3	gate
mb	main terminal 2

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
V _{DRM}	Repetitive peak off-state voltages		-	-500 500 ¹	-600 600 ¹	-800 800	V
I _{T(RMS)}	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{mb} \le 91 ^{\circ}\text{C}$ full sine wave; $T_{j} = 25 ^{\circ}\text{C}$ prior to surge	-		25		А
		t = 20 ms	-		190		A A
l²t dl _⊤ /dt	l ² t for fusing Repetitive rate of rise of on-state current after	t = 16.7 ms t = 10 ms $I_{TM} = 30 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$	-		209 180		A ² s
	triggering	T2+ G+ T2+ G- T2- G- T2- G+	- - -		50 50 50 10		A/μs A/μs A/μs A/μs
$egin{array}{c} I_{GM} \ V_{GM} \ P_{GM} \end{array}$	Peak gate current Peak gate voltage Peak gate power		- - -		2 5 5		Å V W
P _{G(AV)} T _{stg} T _j	Average gate power Storage temperature Operating junction temperature	over any 20 ms period	-40 -		0.5 150 125		ο̈́ο

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/ μ s.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to mounting base	full cycle half cycle	-	- -	1.0 1.4	K/W K/W
K _{th j-a}	Thermal resistance junction to ambient	minimum footprint, FR4 board	-	55	-	K/W

STATIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}$				
01		T2+ G+	-	6	35	mΑ
		T2+ G-	-	10	35	mΑ
		T2- G-	-	11	35	mA
		T2- G+	-	23	70	mA
I _L	Latching current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$				
		T2+ G+	-	8	40	mA
		T2+ G -	-	30	60	mΑ
		T2- G-	- 1	18	40	mΑ
		T2- G+	-	15	60	mA
I _H	Holding current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$				
		127	-	7	30	mA
		T2-	-	12	30_	mΑ
V_T	On-state voltage	$I_{T} = 30 \text{ A}$	-	1.2	1.55	V
V_{GT}	Gate trigger voltage	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}$ $V_D = 400 \text{ V}; I_T = 0.1 \text{ A}; T_i = 125 ^{\circ}\text{C}$ $V_D = V_{DRM(max)}; T_j = 125 ^{\circ}\text{C}$		0.7	1.5	V
_		$V_D = 400 \text{ V; } I_T = 0.1 \text{ A; } T_i = 125 \text{ °C}$	0.25	0.4		V
I_{D}	Off-state leakage current	$V_D = V_{DRM(max)}$; $T_i = 125 ^{\circ}C$	-	0.1	0.5	mA

DYNAMIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$	100	300	-	V/μs
dV _{com} /dt	off-state voltage Critical rate of change of commutating voltage	exponential waveform; gate open circuit $V_{DM} = 400 \text{ V}$; $T_j = 95 ^{\circ}\text{C}$; $I_{T(RMS)} = 25 \text{ A}$; $I_{Com}/\text{dt} = 9 \text{ A/ms}$; gate open circuit	-	10	-	V/μs
t _{gt}	Gate controlled turn-on time	$I_{TM} = 30 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A};$ $dI_G/dt = 5 \text{ A}/\mu\text{s}$	-	2	-	μs

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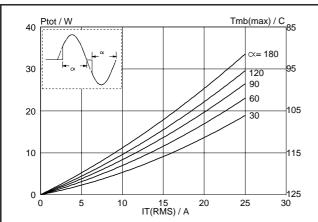


Fig.1. Maximum on-state dissipation, P_{tot} , versus rms on-state current, $I_{T(RMS)}$, where α = conduction angle.

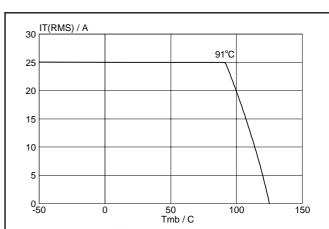


Fig.4. Maximum permissible rms current $I_{T(RMS)}$, versus mounting base temperature T_{mb} .

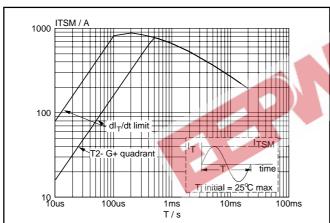


Fig.2. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus pulse width t_p , for sinusoidal currents, $t_p \le 20$ ms.

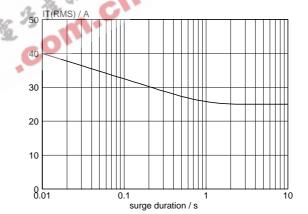


Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{mb} \le 91$ °C.

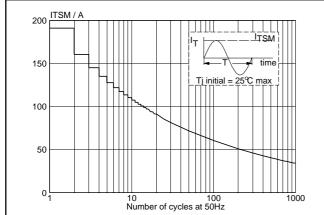


Fig.3. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus number of cycles, for sinusoidal currents, f = 50 Hz.

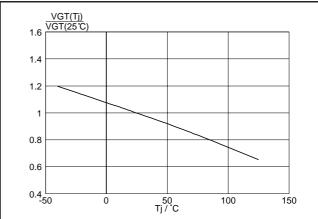
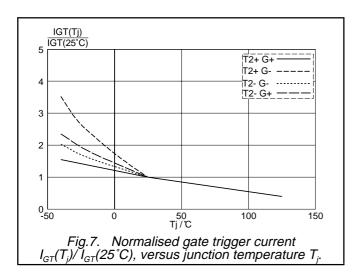
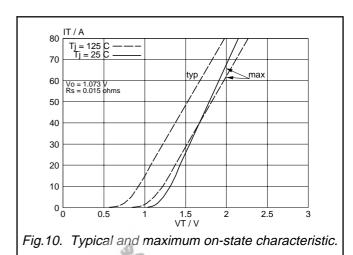


Fig.6. Normalised gate trigger voltage $V_{GT}(T_i)/V_{GT}(25^{\circ}C)$, versus junction temperature T_i .

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1L(Tj) 1L(25°C) 2 1.5 1 0.5 0-50 0 50 Tj/C

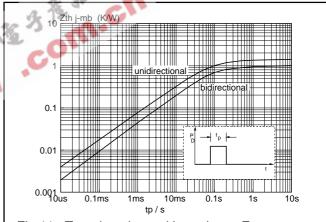
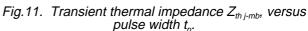


Fig.8. Normalised latching current $I_L(T_i)/I_L(25^{\circ}C)$, versus junction temperature T_i .



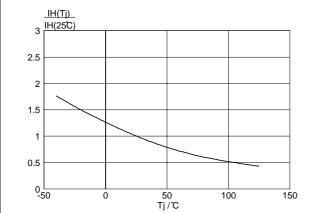


Fig.9. Normalised holding current $I_H(T_i)/I_H(25^{\circ}C)$, versus junction temperature T_i .

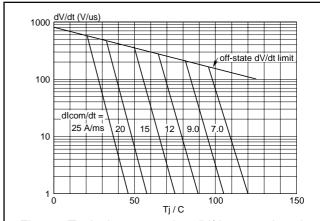
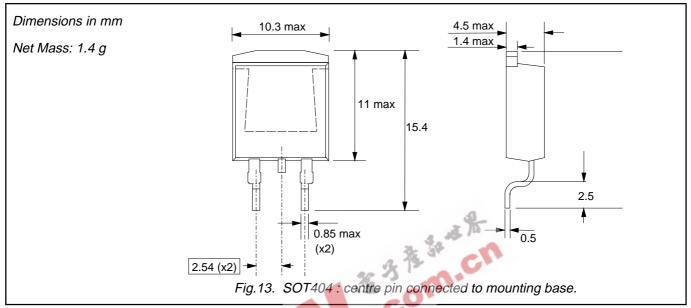


Fig.12. Typical commutation dV/dt versus junction temperature, parameter commutation dI_T/dt . The triac should commutate when the dV/dt is below the value on the appropriate curve for pre-commutation dI_T/dt .

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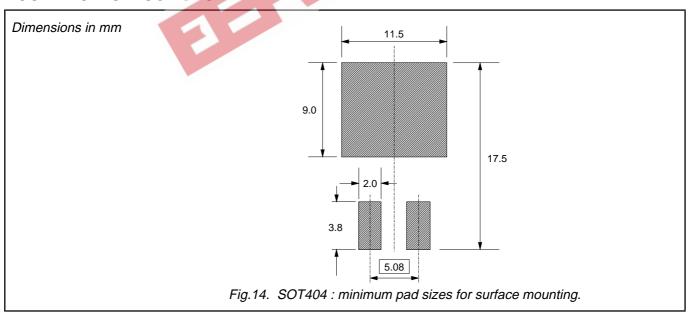
MECHANICAL DATA



Notes

1. Epoxy meets UL94 V0 at 1/8".

MOUNTING INSTRUCTIONS



Notes

1. Plastic meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification This data sheet contains preliminary data; supplementary data may be					
Product specification	This data sheet contains final product specifications.				
Limitima valuas					

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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